N-Channel Silicon MOSFET



CPH6403

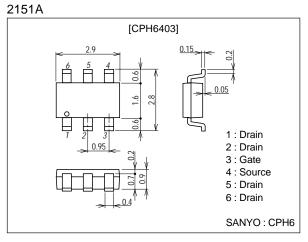
Load Switching Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 2.5V drive.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		20	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	۱ _D		6	A
Drain Current (pulse)	IDP	PW≤10µs, duty cycle≤1%	24	A
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² ×0.8mm)	1.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	20			V
Zero Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	0.5		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =3A	6.3	9		S
Static Drain-to-Source On-State Resistance	R _{DS(on)} 1	ID=3A, VGS=4V		28	38	mΩ
	R _{DS(on)} 2	I _D =1A, V _{GS} =2.5V		38	52	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		700		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		200		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		150		pF
Marking : KC Continued on next pa						

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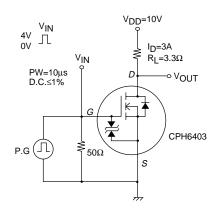
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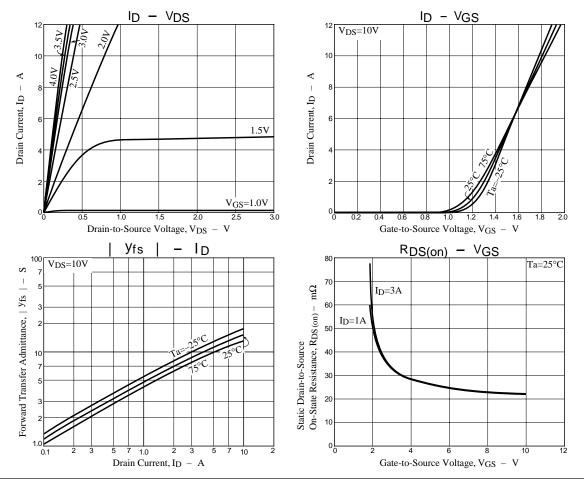
SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

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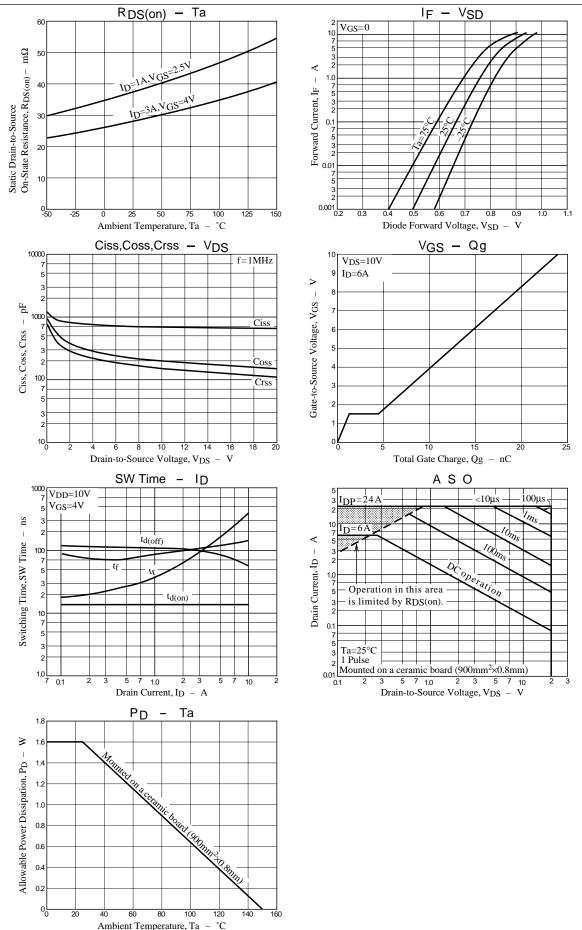
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit		14		ns
Rise Time	tr	See specified Test Circuit		90		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit		90		ns
Fall Time	t _f	See specified Test Circuit		100		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =6A		24		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =6A		1.5		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =6A		3.2		nC
Diode Forward Voltage	V _{SD}	I _S =6A, V _{GS} =0		0.87	1.2	V

Switching Time Test Circuit





No.5990-2/4



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